

An Organosilicon Dendrimer Composed of 16 Thiophene Rings

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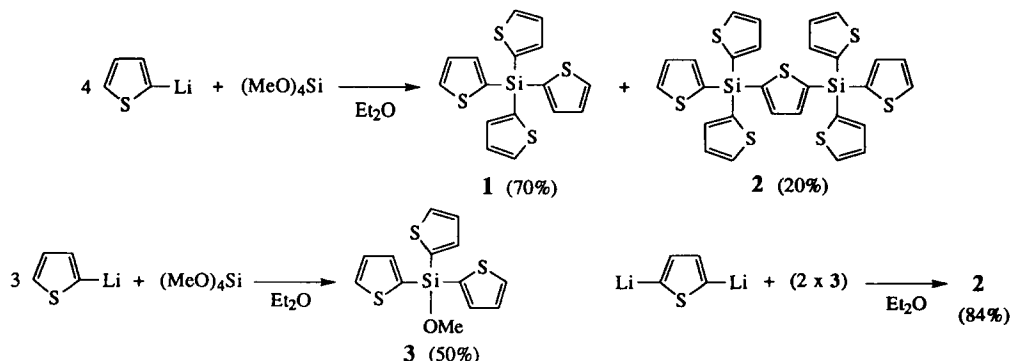
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Abstract: An organosilicon dendrimer composed of 16 thiophene rings, $C_{64}H_{44}S_{16}Si_5$, was prepared by tetralithiation of tetra-2-thienylsilane followed by reaction with 3 molar amounts of methyl tri-2-thienylsilyl ether.
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Dendrimers, polymers with a regularly and highly branched, three-dimensional, tree-like structure, are the subject of recent extensive investigation. Particularly, dendrimers containing silicon atoms have attracted keen interest very recently because of their potential functionalities.¹⁻³ Meanwhile, numerous reports have also appeared on the syntheses and properties of thiophene oligomers because they serve as building blocks for a variety of molecular devices.⁴ In this connection, we have become interested in the preparation of dendrimers containing both silicon atoms and thiophene rings. Here we report the first synthesis of such a dendrimer with 16 thiophene rings and a molecular formula of $C_{64}H_{44}S_{16}Si_5$ (molecular weight, 1466.5).

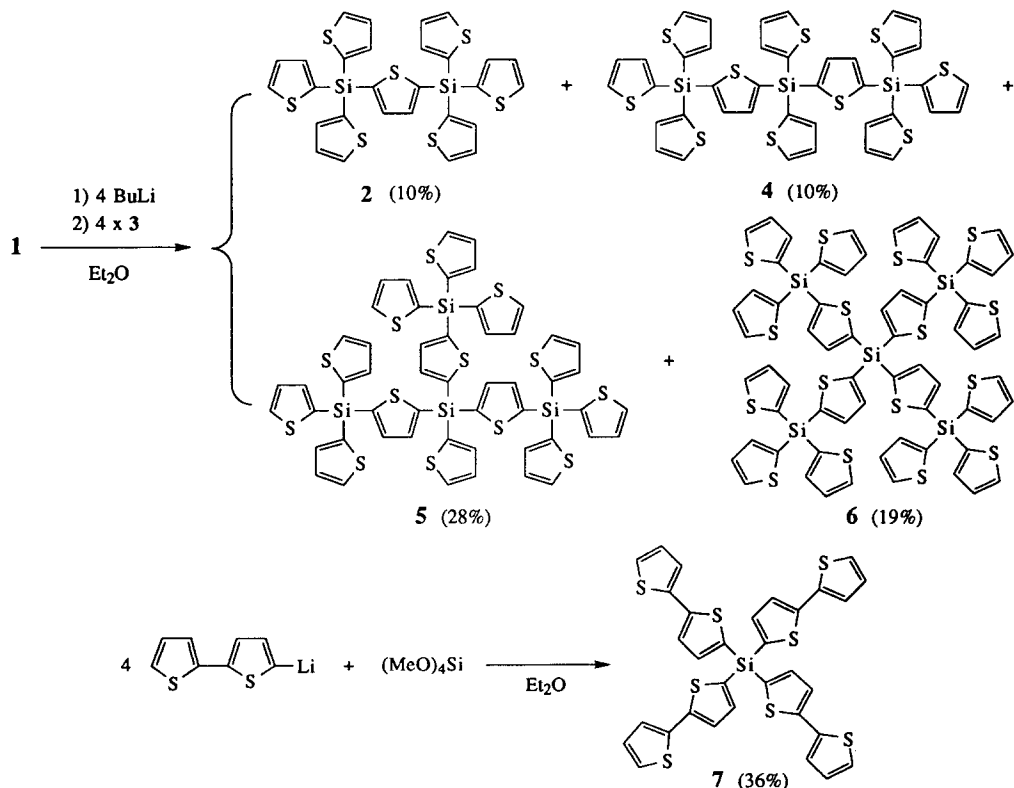
The zeroth generation dendrimer, tetra-2-thienylsilane (**1**), was previously prepared in less than 10% yields by reactions of 2-thienyllithium or 2-thienylmagnesium bromide with tetrachlorosilane or tetraethoxysilane.^{5,6} Combination of these reagents persistently afforded polymeric materials as the principal product which are insoluble in common organic solvents. After some effort we have found that treatment of tetramethoxysilane with 4 molar amounts of 2-thienyllithium (1.0 M solution in THF, Aldrich) affords **1** in 70% yield along with 2,5-bis[tri(2-thienyl)silyl]thiophene (**2**)⁷ in 20% yield.

Methyl tri-2-thienylsilyl ether (**3**),⁷ which is required as the building block for the preparation of higher generation dendrimers, was prepared by treatment of tetramethoxysilane with 3 molar amounts of 2-thienyllithium in THF in more than 50% yield.



The formation of **2** in the foregoing reaction will be explained as the result of hydrogen-lithium exchange between **1** and 2-thienyllithium, followed by reaction of the lithiated **1** with **3** produced from 2-thienyllithium and tetramethoxysilane. Alternatively, compound **2** could be most effectively synthesized in 84% yield by reaction of two molar amounts of **3** with 2,5-dilithiothiophene, prepared from 2,5-dibromothiophene and *tert*-BuLi.

Treatment of **1** with 4 molar amounts of BuLi in ether and quenching of the mixture with D₂O revealed that the α -position of each thiophene ring was lithiated in more than 80% efficiency. Thus, **1** was lithiated with 4 molar amounts of BuLi and then treated with 4 molar amounts of **3** in ether. Purification of the resulting mixture with silica-gel column chromatography and HPLC gave the expected first-generation dendrimer 5,5',5'',5'''-tetrakis[tri-2-thienylsilyl(tetra-2-thienyl)]silane (**6**)⁷ in 19% yield along with **2** (10%), 5,5'-bis[tri-2-thienylsilyl(tetra-2-thienyl)]silane (**4**)⁷ (22%), and 5,5',5''-tris[tri-2-thienylsilyl(tetra-2-thienyl)]silane (**5**)⁷ (28%) with 10% recovery of **1**.⁸ Relative yield of the products depends on reaction conditions (solvent, temperature, reaction time, lithiation reagents and concentration and relative amounts of the substrates). The yield of **6** given above is obtained under optimized conditions.



Structures of **2-6** were determined based on spectroscopic data and elemental analyses; ¹³C NMR analyses⁷ are particularly useful for their regularly branched structures.

It is noteworthy that the dendrimer **6** forms inclusion complexes with CCl₄, CH₂Cl₂, benzene, and acetone, when crystallized from these solvents or mixtures of these solvents and hexane. Combination of ¹H NMR and elemental analyses revealed that the complex with CCl₄ contains one molecule of CCl₄ per one molecule of **6**, while those with CH₂Cl₂, benzene, and acetone contain 1/3 molecule of these solvents, even after drying under vacuum for 24 h at room temperature.⁷ Curiously enough, no inclusion complex formed with CHCl₃. The solvent-free crystal obtained from this mixed solvent showed a higher melting point than those of any inclusion complexes.⁷

Treatment of compound **2** with 6 molar amounts of BuLi in ether and quenching of the mixture with D₂O revealed that hexalithiation of **2** took place in about 80% efficiency. However, an attempted reaction of the hexalithiated **2** with 6 molar amounts of **3** gave a complex mixture containing compounds **3-6** and failed to give the expected dendrimer with 25 thiophene rings. This is due to the poor solubility of the lithiated **2**, which impedes the reaction with **3**. The use of THF as the solvent of lithiation resulted in the cleavage of the silicon-thiophene ring bond to give **1** in 52% yield.

The reaction of tetramethoxysilane with 4 molar amounts of 5-lithio-2,2'-bithiophene, prepared from 5-bromo-2,2'-bithiophene and *tert*-BuLi, gave another zeroth generation dendrimer **7** in 36% yield.⁹

Acknowledgment

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 - Selected physical data for **2-7** and elemental analyses for **6** and its inclusion complexes (other new substances also gave correct elemental analyses). **2**: mp 142.5-143.5 °C (cyclohexane); ¹H NMR (400 MHz, CDCl₃) δ 7.24 (dd, *J* = 4.4, 3.2 Hz, 6H), 7.49 (d, *J* = 3.2 Hz, 6H), 7.58 (s, 2H), 7.74 (d, *J* = 4.4 Hz, 6H); ¹³C NMR (100 MHz, CDCl₃) δ 128.43, 133.13, 133.22, 138.51, 139.32, 141.91; MS (70 eV); *m/z* 636 (M⁺); UV (CH₂Cl₂) λ_{max} (ε) 244.4 nm (41600). **3**: mp 64.5-65 °C (hexane); ¹H NMR (200 MHz, CDCl₃) δ 3.67 (s, 3H), 7.25 (dd, *J* = 4.8, 3.4 Hz, 3H), 7.51 (dd, *J* = 3.4, 0.7 Hz, 3H), 7.73 (dd, *J* = 4.8, 0.7 Hz, 3H); ¹³C NMR (50 MHz, CDCl₃) δ 51.75, 128.32, 132.81, 132.92, 138.02; MS (70 eV); *m/z* 308 (M⁺). **4**: mp 152-153.5 °C (cyclohexane); ¹H NMR (400 MHz, CDCl₃) δ 7.24 (dd, *J* = 4.8, 3.8 Hz, 8H), 7.48 (dd, *J* = 3.8, 0.8 Hz, 8H), 7.56 (s, 4H), 7.74 (dd, *J* = 4.8, 0.8 Hz, 8H); ¹³C NMR (100 MHz, CDCl₃) δ 128.44, 128.46, 132.95, 133.12, 133.22, 133.31, 138.52, 138.62, 139.33, 139.41, 141.74, 141.96; MS (70 eV) *m/z* 912 (M⁺); UV (CH₂Cl₂) λ_{max} (ε) 245.8 nm (73200). **5**: mp 148-152 °C (cyclohexane); ¹H NMR (400 MHz, CDCl₃) δ 7.22 (dd, *J* = 5.0, 3.7 Hz, 10H), 7.47 (dd, *J* = 3.7, 0.8 Hz, 10H), 7.55 (d, *J* = 3.2 Hz, 3H), 7.56 (d, *J* = 3.2 Hz, 3H), 7.72 (dd, *J* = 5.0, 0.8 Hz, 10H); ¹³C NMR (100 MHz, CDCl₃) δ 128.43, 128.47, 132.57, 133.11, 133.20, 133.39, 138.50, 138.70, 139.32, 139.47, 141.54, 142.05; UV (CH₂Cl₂) λ_{max} (ε) 246.0 nm (95600). Anal. Calcd for C₅₂H₃₆S₁₃Si₄: C, 52.48; H, 3.04. Found: C, 52.65; H, 3.16. **6**: mp 218-219 °C (chloroform/hexane); colorless needles; ¹H NMR (400 MHz, CDCl₃) δ 7.22 (dd, *J* = 4.5, 3.2 Hz, 12H), 7.47 (d, *J* = 3.2 Hz, 12H), 7.54 (d, *J* = 3.3 Hz, 4H), 7.56 (d, *J* = 3.5 Hz, 4H), 7.72 (d, *J* = 4.5 Hz, 12H); ¹³C NMR (100 MHz, CDCl₃) δ 128.43, 133.10, 133.20, 138.51, 139.32, 139.54, 141.28, 142.10; UV (CH₂Cl₂) λ_{max} (ε) 245.4 nm (140000). Anal. Calcd for C₆₄H₄₄S₁₆Si₅: C, 52.41; H, 3.02. Found: C, 52.17; H, 3.00. **6** crystallized from a mixture of CCl₄ and hexane: mp 200-201 °C. Anal. Calcd for C₆₄H₄₄S₁₆Si₅·CCl₄: C, 48.18; H, 2.73. Found: C, 47.90; H, 2.68. **6** crystallized from a mixture of C₆H₆ and hexane: mp 205-206 °C. Anal. Calcd for C₆₄H₄₄S₁₆Si₅·1/3C₆H₆: C, 53.11; H, 3.11. Found: 53.37; H, 3.22. **6** crystallized from acetone: mp 205-206 °C. Anal. Calcd for C₆₄H₄₄S₁₆Si₅·1/3C₃H₆O: C, 52.54; H, 3.12. Found: C, 52.71; H, 3.08. **6** crystallized from a mixture of CH₂Cl₂ and hexane: mp 206.5-207 °C. Anal. Calcd for C₆₄H₄₄S₁₆Si₅·1/3CH₂Cl₂: C, 51.69; H, 3.01. Found: C, 51.94; H, 2.94. **7**: mp 154-154.5 °C (C₆H₆/hexane); ¹H NMR (200 MHz, CDCl₃) δ 7.00 (dd, *J* = 5.2, 3.8 Hz, 4H), 7.22 (d, *J* = 5.2 Hz, 4H), 7.23 (d, *J* = 3.8 Hz, 4H), 7.30 (d, *J* = 3.5 Hz, 4H), 7.43 (d, *J* = 3.5 Hz, 4H); ¹³C NMR (50 MHz, CDCl₃) δ 124.59, 125.08, 125.26, 127.90, 131.73, 136.82, 139.35, 145.56; MS (70 eV) *m/z* 688 (M⁺); UV/Vis; λ_{max} (ε) 327.5 nm (88900).
 - A 1.65 M hexane solution of BuLi (4 ml, 6.6 mmol) was added to a solution of **1** (540 mg, 1.5 mmol) in ether (15 ml) at -18 °C under argon. The mixture was stirred for 1 h. A solution of **3** (2.03 g, 6.6 mmol) in ether (10 ml) was added to the above mixture, and the resulting mixture was warmed to room temperature and stirred for 12 h. The reaction was quenched by adding ice-water and then CH₂Cl₂ (150 ml) was added and the organic layer was washed with water, dried, and evaporated. The residue was placed on a column of silica gel and eluted with a mixture of CH₂Cl₂/hexane (1/3) to give 55 mg (10%) of **1**, 92 mg (10%) of **2**, 309 mg (22%) of **4**, 500 mg (28%) of **5**, and 446 mg (19%) of **6** (separation of **4-6** by column chromatography is incomplete; these were separated by HPLC on a column of JAIGEL-2H (Japan Analytical Industry Co.) to give them in the yields given above).
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